

Product Summary (@ $T_A = +25^\circ\text{C}$)

V_{RRM} (V)	I_o (A)	V_F MAX (V)	I_R MAX (μA)
60	4	0.52	150

Description and Applications

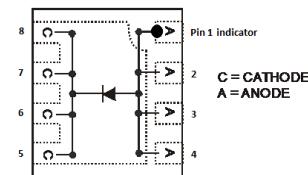
The SBRT4U60LP is a 4A, 60V single rectifier packaged in the low profile U-DFN3030-8 package. Providing low V_F and excellent high temperature stability, this device is ideal for use in general rectification applications such as:

- Bypass Diode
- Boost Diode
- Blocking Diode
- Recirculating Diode

U-DFN3030-8



Bottom View



Top View
Schematic and Pin Configuration

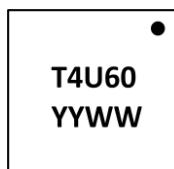
Ordering Information (Note 4)

Part Number	Case	Packaging
SBRT4U60LP-7	U-DFN3030-8	3000/Tape & Reel

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



T4U60 = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Last Two Digits of Year (ex: 18 for 2018)
 WW = Week Code (01 to 53)

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V_{RRM}		
Working Peak Reverse Voltage	V_{RWM}	60	V
DC Blocking Voltage	V_{RM}		
Average Rectified Output Current	I_O	4	A
Non-Repetitive Peak Forward Surge Current 8.3ms	I_{FSM}	25	A
Single Half Sine-Wave Superimposed on Rated Load			

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Ambient (Note 5)	$R_{\theta JA}$	110	$^\circ\text{C}/\text{W}$
Typical Thermal Resistance Junction to Case (Note 5)	$R_{\theta JC}$	10	$^\circ\text{C}/\text{W}$
Typical Thermal Resistance Junction to Ambient (Note 6)	$R_{\theta JA}$	70	$^\circ\text{C}/\text{W}$
Typical Thermal Resistance Junction to Case (Note 6)	$R_{\theta JC}$	4	$^\circ\text{C}/\text{W}$
Total Power Dissipation (Note 5)	P_{TOT}	1.4	W
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +175	$^\circ\text{C}$

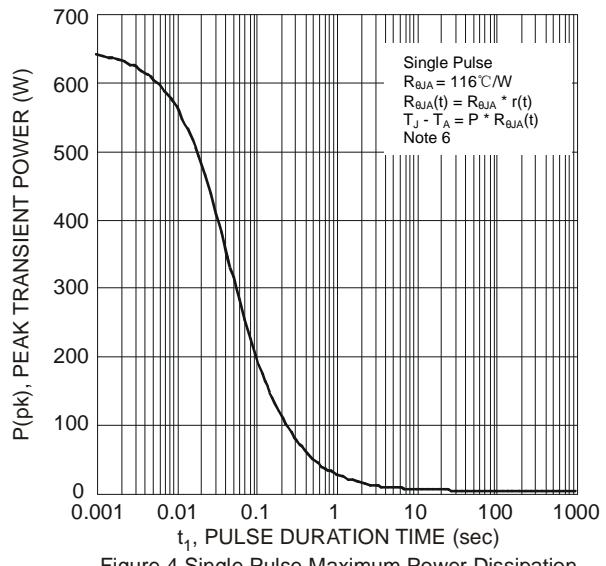
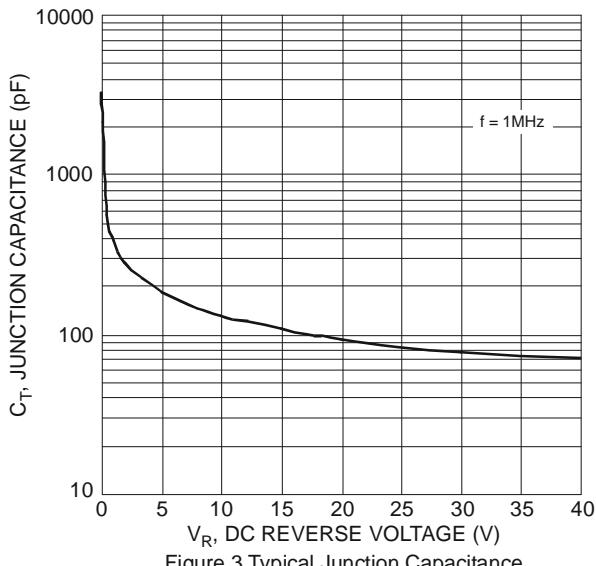
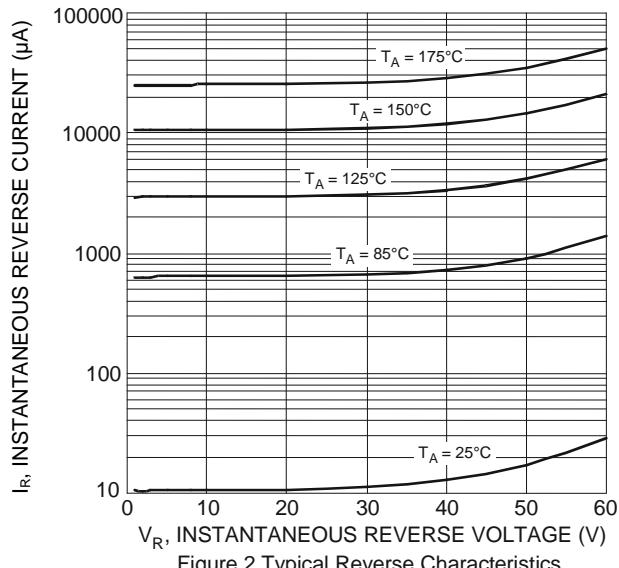
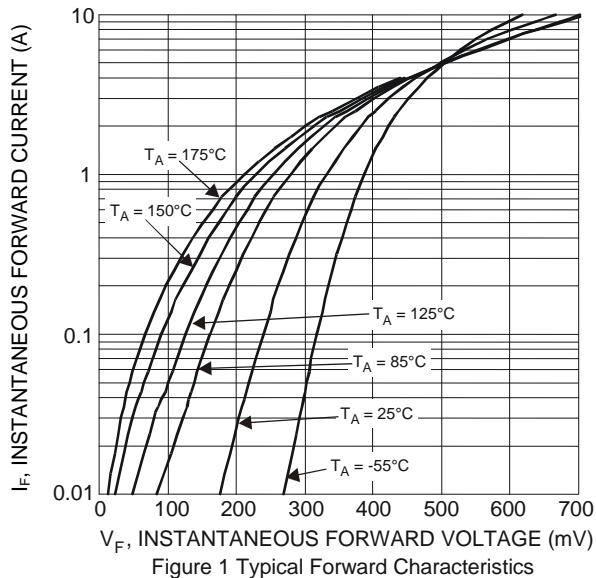
Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

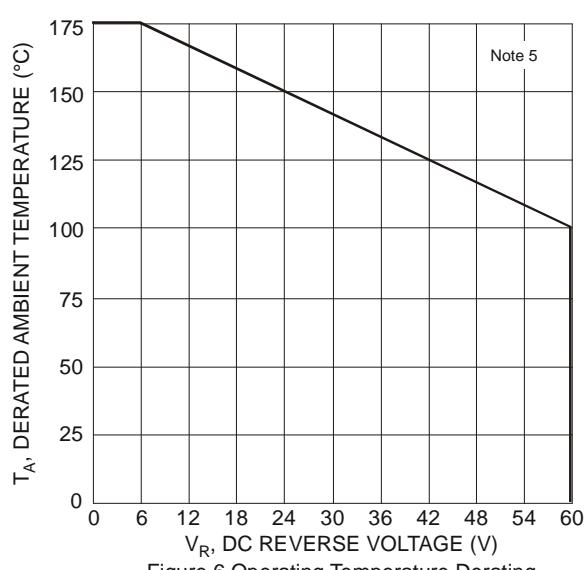
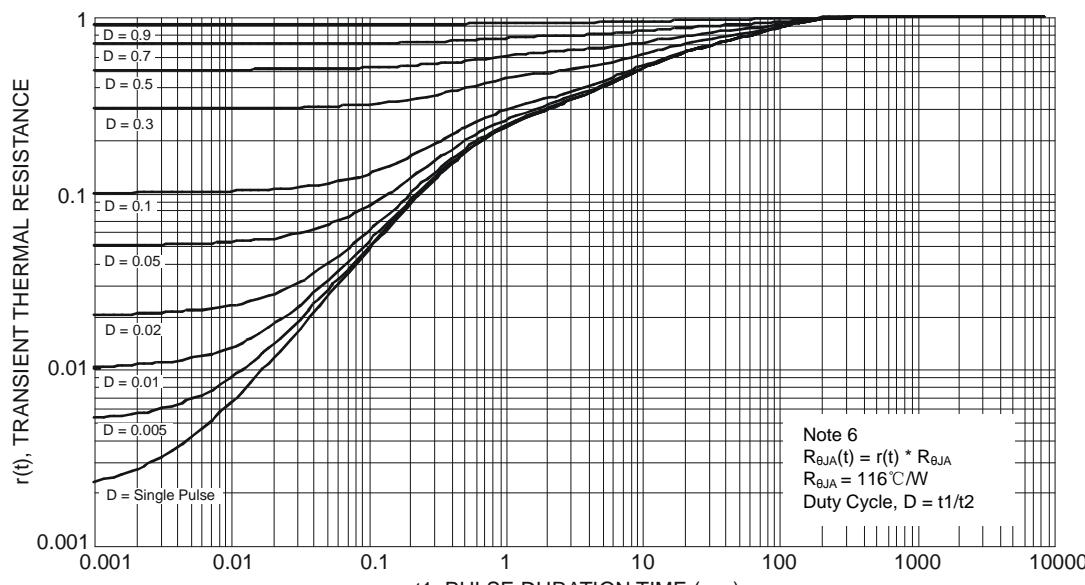
Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Forward Voltage Drop	V_F	—	0.38	—	V	$I_F = 2\text{A}, T_J = +25^\circ\text{C}$
		—	0.46	0.52		$I_F = 4\text{A}, T_J = +25^\circ\text{C}$
		—	0.33	—		$I_F = 2\text{A}, T_J = +125^\circ\text{C}$
		—	0.45	—		$I_F = 4\text{A}, T_J = +125^\circ\text{C}$
Leakage Current (Note 7)	I_R	—	30	150	μA	$V_R = 60\text{V}, T_J = +25^\circ\text{C}$
Total Capacitance	C_T	—	6	—	mA	$V_R = 60\text{V}, T_J = +125^\circ\text{C}$
		—	180	—	pF	$V_R = 5\text{V}, f = 1\text{MHz}$

Notes: 5. Device mounted on FR-4 substrate, 2 oz. Copper, minimum recommended pad layout per <http://www.diodes.com/package-outlines.html>.

6. Device mounted on FR-4 substrate, 2 oz. Copper, 1 sq. inch Cu pad.

7. Short duration pulse test used to minimize self-heating effect.

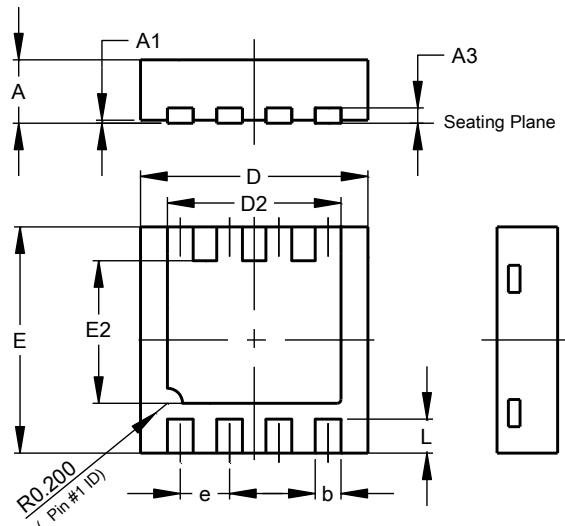




Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

U-DFN3030-8



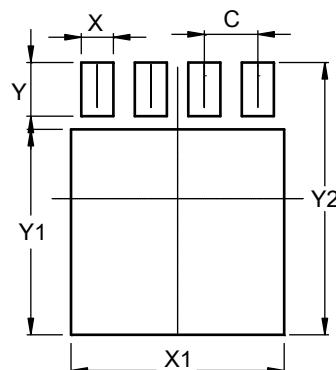
U-DFN3030-8			
Dim	Min	Max	Typ
A	0.57	0.63	0.60
A1	0	0.05	0.02
A3	-	-	0.15
b	0.29	0.39	0.34
D	2.90	3.10	3.00
D2	2.19	2.39	2.29
e	-	-	0.65
E	2.90	3.10	3.00
E2	1.64	1.84	1.74
L	0.30	0.60	0.45

All Dimensions in mm

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

U-DFN3030-8



Dimensions	Value (in mm)
C	0.650
X	0.390
X1	2.590
Y	0.650
Y1	2.490
Y2	3.300

IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

A. Life support devices or systems are devices or systems which:

1. are intended to implant into the body, or
2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.

B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2018, Diodes Incorporated

www.diodes.com

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Diodes Incorporated:](#)

[SBRT4U60LP-7](#)